

## 0.7-Ω DUAL SPDT ANALOG SWITCH WITH NEGATIVE RAIL CAPABILITY AND 1.8-V COMPATIBLE INPUT LOGIC

Check for Samples: [TS5A22366](#)

### FEATURES

- **Negative Signaling Capability:** Maximum Swing From  $-2.75\text{ V}$  to  $2.75\text{ V}$  ( $V_+ = 2.75\text{ V}$ )
- **Low ON-State Resistance ( $0.7\ \Omega$  Typ)**
- **Excellent ON-State Resistance Matching**
- **1.8-V Compatible Control Input Threshold Independent of  $V_+$**
- **Control Inputs Are 5.5-V Tolerant**
- **2.25-V to 5.5-V Power Supply ( $V_+$ )**
- **Low Charge Injection**
- **Specified Break-Before-Make Switching**
- **Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II**

- **ESD Performance Tested Per JESD 22**
  - 2500-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)
  - 200-V Machine Model (A115-A)

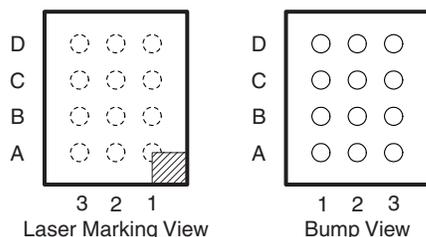
### APPLICATIONS

- Cell Phones
- PDAs
- Portable Instrumentation
- Audio Routing
- Portable Media Players

#### YFC PACKAGE TERMINAL ASSIGNMENTS

|   |          |                     |          |
|---|----------|---------------------|----------|
| D | NC1      | $V_+$               | NC2      |
| C | COM1     | GND                 | COM2     |
| B | NO1      | GND                 | NO2      |
| A | IN1      | N.C. <sup>(1)</sup> | IN2      |
|   | <b>1</b> | <b>2</b>            | <b>3</b> |

#### YFC PACKAGE



(1) N.C. –No internal connection

### DESCRIPTION

The TS5A22366 is a dual single-pole double-throw (SPDT) analog switch that is designed to operate from 2.25 V to 5.5 V. The device features negative signal capability that allows signals below ground to pass through the switch without distortion.

The break-before-make feature prevents signal distortion during the transferring of a signal from one path to another. Low ON-state resistance, excellent channel-to-channel ON-state resistance matching, and minimal total harmonic distortion (THD) performance are ideal for audio applications.

The TS5A22366 is available as a ultra small 1.6 mm × 1.2 mm wafer-chip-scale package (WCSP) (0.4 mm pitch).

### ORDERING INFORMATION

For package and ordering information, see the Package Option Addendum at the end of this document.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

**Table 1. SUMMARY OF CHARACTERISTICS** $V_+ = 3.3\text{ V}$ ,  $T_A = 25^\circ\text{C}$ 

| Configuration                                   | 2:1 Multiplexer/Demultiplexer<br>(2 × SPDT) |
|---|---|
| Number of channels                              | 2   |
| ON-state resistance ( $r_{on}$ )                | 0.8 $\Omega$                                |
| ON-state resistance match ( $\Delta r_{on}$ )   | 0.08 $\Omega$                               |
| ON-state resistance flatness ( $r_{ON(flat)}$ ) | 0.3 $\Omega$                                |
| Turn-on/turn-off time ( $t_{ON}/t_{OFF}$ )      | 199 ns/182 ns                               |
| Break-before-make time ( $t_{BBM}$ )            | 7.1 ns                                      |
| Charge injection ( $Q_C$ )                      | 120 pC                                      |
| Bandwidth (BW)                                  | 32 MHz                                      |
| OFF isolation ( $O_{ISO}$ )                     | -70 dB at 100 kHz                           |
| Crosstalk ( $X_{TALK}$ )                        | -70 dB at 100 kHz                           |
| Total harmonic distortion (THD)                 | 0.01%                                       |
| Package option                                  | 12-pin WCSP (YFC)                           |

**Table 2. FUNCTION TABLE**

| IN | NC TO COM,<br>COM TO NC | NO TO COM,<br>COM TO NO |
|----|-------------------------|-------------------------|
| L  | ON                      | OFF                     |
| H  | OFF                     | ON                      |

APPLICATION BLOCK DIAGRAM

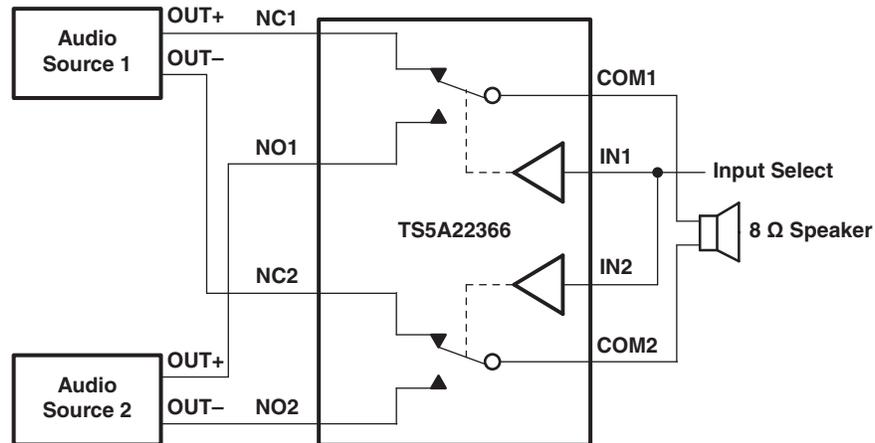


Figure 1. TS5A22366 Application Block Diagram

Negative Signaling Capacity

The TS5A22366 dual SPDT switch features negative signal capability that allows signals below ground to pass through without distortion. These analog switches operate from a single +2.3-V to +5.5-V supply. The input/output signal swing of the device is dependant of the supply voltage  $V_+$ : the devices pass signals as high as  $V_+$  and as low as  $V_+ - 5.5$  V, including signals below ground with minimal distortion.

Table 3 shows the input/output signal swing the user can get with different supply voltages.

Table 3. Input/Output Signal Swing

| SUPPLY VOLTAGE, $V_+$ | MINIMUM<br>( $V_{NC}, V_{NO}, V_{COM}$ ) = $V_+ - 5.5$ | MAXIMUM<br>( $V_{NC}, V_{NO}, V_{COM}$ ) = $V_+$ |
|-----------------------|--|--|
| 5.5 V                 | 0 V  | 5.5 V  |
| 4.2 V                 | -1.3 V   | 4.2 V  |
| 3.3 V                 | -2.2 V   | 3.3 V  |
| 3 V                   | -2.5 V   | 3 V  |
| 2.5 V                 | -3 V   | 2.5 V  |

**ABSOLUTE MINIMUM AND MAXIMUM RATINGS<sup>(1) (2)</sup>**

over operating free-air temperature range (unless otherwise noted)

|                                   |  | MIN                                 | MAX         | UNIT |
|-----------------------------------|--|-------------------------------------|-------------|------|
| $V_+$                             | Supply voltage range <sup>(3)</sup>            | -0.5                                | 6           | V    |
| $V_{NC}$<br>$V_{NO}$<br>$V_{COM}$ | Analog voltage range <sup>(3) (4) (5)</sup>    | $V_+ - 6$                           | $V_+ + 0.5$ | V    |
| $I_K$                             | Analog port diode current <sup>(6)</sup>       | $V_+ < V_{NC}, V_{NO}, V_{COM} < 0$ |             | V    |
| $I_{NC}$<br>$I_{NO}$<br>$I_{COM}$ | ON-state switch current                        | -150                                | 150         | mA   |
|                                   | ON-state peak switch current <sup>(7)</sup>    | -300                                | 300         |      |
| $V_I$                             | Digital input voltage range                    | -0.5                                | 6.5         | V    |
| $I_{IK}$                          | Digital input clamp current <sup>(3) (4)</sup> | $V_{IO} < V_I < 0$                  |             | mA   |
| $I_{GND}$<br>$I_+$                | Continuous current through $V_+$ or GND        | -100                                | 100         | mA   |
| $T_{stg}$                         | Storage temperature range                      | -65                                 | 150         | °C   |

- (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.
- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
- (3) All voltages are with respect to ground, unless otherwise specified.
- (4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (5) This value is limited to 5.5 V maximum.
- (6) Requires clamp diodes on analog port to  $V_+$ .
- (7) Pulse at 1-ms duration <10% duty cycle

**THERMAL IMPEDANCE RATINGS**

|               |  |             | UNIT       |
|---------------|--|-------------|------------|
| $\theta_{JA}$ | Package thermal impedance <sup>(1)</sup> | YFC package | 106.2 °C/W |

- (1) The package thermal impedance is calculated in accordance with JESD 51-7.

**ELECTRICAL CHARACTERISTICS FOR 2.5-V SUPPLY<sup>(1)</sup>**
 $V_+ = 2.25\text{ V to }2.7\text{ V}$ ,  $T_A = -40^\circ\text{C to }85^\circ\text{C}$  (unless otherwise noted)

| PARAMETER  | SYMBOL                     | TEST CONDITIONS  | $T_A$ | $V_+$  | MIN         | TYP  | MAX   | UNIT     |
|--|----------------------------|--|-------|--------|-------------|------|-------|----------|
| <b>Analog Switch</b>                                 |                            |  |       |        |             |      |       |          |
| Analog signal range                                  | $V_{COM}, V_{NO}, V_{NC}$  |  |       |        | $V_+ - 5.5$ |      | $V_+$ | $\Omega$ |
| ON-state resistance                                  | $r_{on}$                   | $V_{NC}$ or $V_{NO} = V_+, 1.5\text{ V}$ ,<br>$V_+ - 5.5\text{ V}$<br>$I_{COM} = -100\text{ mA}$ ,<br>Switch ON,<br>See <a href="#">Figure 15</a>  | 25°C  | 2.25 V |             | 1    | 1.8   | $\Omega$ |
|  |                            |  | Full  |        |             |      | 2     |          |
| ON-state resistance match between channels           | $\Delta r_{on}$            | $V_{NC}$ or $V_{NO} = 1.5\text{ V}$ ,<br>$I_{COM} = -100\text{ mA}$ ,<br>Switch ON,<br>See <a href="#">Figure 15</a>   | 25°C  | 2.25 V |             | 0.05 | 1     | $\Omega$ |
|  |                            |  | Full  |        |             |      | 1     |          |
| ON-state resistance flatness                         | $r_{on(flat)}$             | $V_{NC}$ or $V_{NO} = V_+, 1.5\text{ V}$ ,<br>$V_+ - 5.5\text{ V}$<br>$I_{COM} = -100\text{ mA}$ ,<br>Switch ON,<br>See <a href="#">Figure 16</a>  | 25°C  | 2.25 V |             | 0.53 | 1.5   | $\Omega$ |
|  |                            |  | Full  |        |             |      | 1.6   |          |
| NC, NO OFF leakage current                           | $I_{NC(OFF)}, I_{NO(OFF)}$ | $V_{NC} = 2.25, V_+ - 5.5\text{ V}$<br>$V_{COM} = V_+ - 5.5\text{ V}$ ,<br>2.25,<br>$V_{NO} = \text{Open}$ ,<br>or<br>$V_{NO} = 2.25, V_+ - 5.5\text{ V}$<br>$V_{COM} = V_+ - 5.5\text{ V}$ ,<br>2.25,<br>$V_{NC} = \text{Open}$ ,<br>Switch OFF,<br>See <a href="#">Figure 16</a> | 25°C  | 2.7 V  |             | -50  | 50    | nA       |
|  |                            |  | Full  |        |             |      | -375  |          |
| COM ON leakage current                               | $I_{COM(ON)}$              | $V_{NC}$ and $V_{NO} = \text{Open}$ ,<br>$V_{COM} = V_+, V_+ - 5.5\text{ V}$ ,<br>See <a href="#">Figure 17</a>  | 25°C  | 2.7 V  |             | -50  | 50    | nA       |
|  |                            |  | Full  |        |             |      | -375  |          |
| <b>Digital Control Inputs (IN, EN)<sup>(2)</sup></b> |                            |  |       |        |             |      |       |          |
| Input logic high                                     | $V_{IH}$                   |  | Full  |        | 1.05        |      | 5.5   | V        |
| Input logic low                                      | $V_{IL}$                   |  | Full  |        |             |      | 0.65  | V        |
| Input leakage current                                | $I_{IH}, I_{IL}$           | $V_{IN} = 1.8\text{ V or GND}$   | 25°C  | 2.7 V  |             | -700 | 700   | nA       |
|  |                            |  | Full  |        |             |      | -700  |          |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(2) All unused digital inputs of the device must be held at  $V_+$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

**ELECTRICAL CHARACTERISTICS FOR 2.5-V SUPPLY<sup>(1)</sup> (continued)**
 $V_+ = 2.25\text{ V to }2.7\text{ V}$ ,  $T_A = -40^\circ\text{C to }85^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                 | SYMBOL                           | TEST CONDITIONS  |  | $T_A$ | $V_+$           | MIN | TYP  | MAX | UNIT          |
|---------------------------|----------------------------------|--|--|-------|-----------------|-----|------|-----|---------------|
| <b>Dynamic</b>            |                                  |  |  |       |                 |     |      |     |               |
| Turn-on time              | $t_{ON}$                         | $V_{COM} = V_+$ ,<br>$R_L = 300\ \Omega$ ,                           | $C_L = 35\text{ pF}$ ,<br>See <a href="#">Figure 19</a>                | 25°C  | 2.5 V           |     | 193  | 297 | ns            |
|                           |                                  |  |  | Full  | 2.25 V to 2.7 V |     |      | 350 |               |
| Turn-off time             | $t_{OFF}$                        | $V_{COM} = V_+$ ,<br>$R_L = 300\ \Omega$ ,                           | $C_L = 35\text{ pF}$ ,<br>See <a href="#">Figure 19</a>                | 25°C  | 2.5 V           |     |      | 266 | ns            |
|                           |                                  |  |  | Full  | 2.25 V to 2.7 V |     |      | 320 |               |
| Break-before-make time    | $t_{BBM}$                        | $V_{NC} = V_{NO} = V_+/2$<br>$R_L = 300\ \Omega$ ,                   | $C_L = 35\text{ pF}$ ,<br>See <a href="#">Figure 20</a>                | 25°C  | 2.5 V           | 1   | 15.6 |     | ns            |
| Charge injection          | $Q_C$                            | $V_{GEN} = 0$ ,<br>$R_{GEN} = 0$ ,                                   | $C_L = 1\text{ nF}$ ,<br>See <a href="#">Figure 24</a>                 | 25°C  | 2.5 V           |     | 91   |     | pC            |
| NC, NO OFF capacitance    | $C_{NC(OFF)}$ ,<br>$C_{NO(OFF)}$ | $V_{NC}$ or $V_{NO} = V_+$ or<br>GND,<br>Switch OFF,                 | See <a href="#">Figure 18</a>  | 25°C  | 2.5 V           |     | 51   |     | pF            |
| NC, NO ON capacitance     | $C_{NC(ON)}$ ,<br>$C_{NO(ON)}$   | $V_{NC}$ or $V_{NO} = V_+$ or<br>GND,<br>Switch OFF,                 | See <a href="#">Figure 18</a>  | 25°C  | 2.5 V           |     | 181  |     | pF            |
| COM ON capacitance        | $C_{COM(ON)}$                    | $V_{COM} = V_+$ or GND,<br>Switch ON,                                | See <a href="#">Figure 18</a>  | 25°C  | 2.5 V           |     | 181  |     | pF            |
| Digital input capacitance | $C_I$                            | $V_I = V_+$ or GND   | See <a href="#">Figure 18</a>  | 25°C  | 2.5 V           |     | 3    |     | pF            |
| Bandwidth                 | BW                               | $R_L = 50\ \Omega$ ,   | Switch ON,<br>See <a href="#">Figure 20</a>                            | 25°C  | 2.5 V           |     | 32   |     | MHz           |
| OFF isolation             | $O_{ISO}$                        | $R_L = 50\ \Omega$ , Switch<br>OFF,<br>See <a href="#">Figure 22</a> | $f = 100\text{ kHz}$ ,   | 25°C  | 2.5 V           |     | -70  |     | dB            |
|                           |                                  |  | $f = 1\text{ MHz}$ ,   |       |                 |     | -50  |     |               |
|                           |                                  |  | $f = 5\text{ MHz}$ ,   |       |                 |     | -35  |     |               |
| Crosstalk                 | $X_{TALK}$                       | $R_L = 50\ \Omega$ , Switch ON,<br>See <a href="#">Figure 23</a>     | $f = 100\text{ kHz}$ ,   | 25°C  | 2.5 V           |     | -70  |     | dB            |
|                           |                                  |  | $f = 1\text{ MHz}$ ,   |       |                 |     | -50  |     |               |
|                           |                                  |  | $f = 5\text{ MHz}$ ,   |       |                 |     | -35  |     |               |
| Total harmonic distortion | THD                              | $R_L = 600\ \Omega$ ,<br>$C_L = 50\text{ pF}$ ,                      | $f = 20\text{ Hz to }20\text{ kHz}$ ,<br>See <a href="#">Figure 25</a> | 25°C  | 2.5 V           |     | 0.02 |     | %             |
| <b>Supply</b>             |                                  |  |  |       |                 |     |      |     |               |
| Positive supply current   | $I_+$                            | $V_I = 1.8\text{ V or GND}$ ,  |  | Full  | 2.7 V           |     | 6    | 12  | $\mu\text{A}$ |

**ELECTRICAL CHARACTERISTICS FOR 3.3-V SUPPLY<sup>(1)</sup>**
 $V_+ = 3\text{ V to }3.6\text{ V}$ ,  $T_A = -40^\circ\text{C to }85^\circ\text{C}$  (unless otherwise noted)

| PARAMETER  | SYMBOL                     | TEST CONDITIONS  | $T_A$        | $V_+$ | MIN          | TYP  | MAX          | UNIT     |
|--|----------------------------|--|--------------|-------|--------------|------|--------------|----------|
| <b>Analog Switch</b>                                 |                            |  |              |       |              |      |              |          |
| Analog signal range                                  | $V_{COM}, V_{NO}, V_{NC}$  |  |              |       | $V_+ - 5.5$  |      | $V_+$        | $\Omega$ |
| ON-state resistance                                  | $r_{on}$                   | $V_{NC}$ or $V_{NO} \leq V_+, 1.5\text{ V}$ ,<br>$V_+ - 5.5\text{ V}$ ,<br>$I_{COM} = -100\text{ mA}$ ,<br>Switch ON,<br>See <a href="#">Figure 15</a>   | 25°C<br>Full | 3 V   |              | 0.8  | 1.3<br>1.53  | $\Omega$ |
| ON-state resistance match between channels           | $\Delta r_{on}$            | $V_{NC}$ or $V_{NO} = 1.5\text{ V}$ ,<br>$I_{COM} = -100\text{ mA}$ ,<br>Switch ON,<br>See <a href="#">Figure 15</a>   | 25°C<br>Full | 3 V   |              | 0.08 | 0.17<br>0.3  | $\Omega$ |
| ON-state resistance flatness                         | $r_{on(flat)}$             | $V_{NC}$ or $V_{NO} \leq V_+, 1.5\text{ V}$ ,<br>$V_+ - 5.5\text{ V}$ ,<br>$I_{COM} = -100\text{ mA}$ ,<br>Switch ON,<br>See <a href="#">Figure 16</a>   | 25°C<br>Full | 3 V   |              | 0.3  | 0.65<br>0.75 | $\Omega$ |
| NC, NO OFF leakage current                           | $I_{NC(OFF)}, I_{NO(OFF)}$ | $V_{NC} = 3, V_+ - 5.5\text{ V}$<br>$V_{COM} = V_+ - 5.5\text{ V}, 3,$<br>$V_{NO} = \text{Open}$ ,<br>or<br>$V_{NO} = 3, V_+ - 5.5\text{ V}$<br>$V_{COM} = V_+ - 5.5\text{ V}, 3,$<br>$V_{NC} = \text{Open}$ ,<br>Switch OFF,<br>See <a href="#">Figure 16</a> | 25°C<br>Full | 3.6 V | -50<br>-375  |      | 50<br>375    | nA       |
| COM ON leakage current                               | $I_{COM(ON)}$              | $V_{NC}$ and $V_{NO} = \text{Open}$ ,<br>$V_{COM} = V_+, V_+ - 5.5\text{ V}$ ,<br>Switch ON,<br>See <a href="#">Figure 17</a>  | 25°C<br>Full | 3.6 V | -50<br>-375  |      | 50<br>375    | nA       |
| <b>Digital Control Inputs (IN, EN)<sup>(2)</sup></b> |                            |  |              |       |              |      |              |          |
| Input logic high                                     | $V_{IH}$                   |  | Full         |       | 1.05         |      | 5.5          | V        |
| Input logic low                                      | $V_{IL}$                   |  | Full         |       |              |      | 0.65         | V        |
| Input leakage current                                | $I_{IH}, I_{IL}$           | $V_{IN} = 1.8\text{ V or GND}$   | 25°C<br>Full | 3.6 V | -920<br>-920 |      | 920<br>920   | nA       |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(2) All unused digital inputs of the device must be held at  $V_+$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

**ELECTRICAL CHARACTERISTICS FOR 3.3-V SUPPLY<sup>(1)</sup> (continued)**
 $V_+ = 3\text{ V to }3.6\text{ V}$ ,  $T_A = -40^\circ\text{C to }85^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                 | SYMBOL                           | TEST CONDITIONS   | $T_A$   | $V_+$ | MIN          | TYP | MAX   | UNIT          |
|---------------------------|----------------------------------|---|---|-------|--------------|-----|-------|---------------|
| <b>Dynamic</b>            |                                  |   |   |       |              |     |       |               |
| Turn-on time              | $t_{ON}$                         | $V_{COM} = V_+$ ,<br>$R_L = 300\ \Omega$ ,                              | $C_L = 35\ \text{pF}$ ,<br>See <a href="#">Figure 19</a>                  | 25°C  | 3.3 V        | 199 | 313   | ns            |
|                           |                                  |   |   | Full  | 3 V to 3.6 V |     | 370   |               |
| Turn-off time             | $t_{OFF}$                        | $V_{COM} = V_+$ ,<br>$R_L = 300\ \Omega$ ,                              | $C_L = 35\ \text{pF}$ ,<br>See <a href="#">Figure 19</a>                  | 25°C  | 3.3 V        | 182 | 289.9 | ns            |
|                           |                                  |   |   | Full  | 3 V to 3.6 V |     | 350   |               |
| Break-before-make time    | $t_{BBM}$                        | $V_{NC} = V_{NO} = V_+/2$<br>$R_L = 300\ \Omega$ ,                      | $C_L = 35\ \text{pF}$ ,<br>See <a href="#">Figure 20</a>                  | 25°C  | 3.3 V        | 1   | 7.1   | ns            |
| Charge injection          | $Q_C$                            | $V_{GEN} = 0$ ,<br>$R_{GEN} = 0$ ,                                      | $C_L = 1\ \text{nF}$ ,<br>See <a href="#">Figure 24</a>                   | 25°C  | 3.3 V        |     | 120   | pC            |
| NC, NO OFF capacitance    | $C_{NC(OFF)}$ ,<br>$C_{NO(OFF)}$ | $V_{NC}$ or $V_{NO} = V_+$ or<br>$V_+ - 5.5\ \text{V}$ ,<br>Switch OFF, | See <a href="#">Figure 18</a>   | 25°C  | 3.3 V        |     | 50    | pF            |
| NC, NO ON capacitance     | $C_{NC(ON)}$ ,<br>$C_{NO(ON)}$   | $V_{NC}$ or $V_{NO} = V_+$ or<br>GND,<br>Switch OFF,                    | See <a href="#">Figure 18</a>   | 25°C  | 3.3 V        |     | 180   | pF            |
| COM ON capacitance        | $C_{COM(ON)}$                    | $V_{COM} = V_+$ or GND,<br>Switch ON,                                   | See <a href="#">Figure 18</a>   | 25°C  | 3.3 V        |     | 180   | pF            |
| Digital input capacitance | $C_I$                            | $V_I = V_+$ or GND  | See <a href="#">Figure 18</a>   | 25°C  | 3.3 V        |     | 3     | pF            |
| Bandwidth                 | BW                               | $R_L = 50\ \Omega$ ,  | Switch ON,<br>See <a href="#">Figure 20</a>                               | 25°C  | 3.3 V        |     | 32    | MHz           |
| OFF isolation             | $O_{ISO}$                        | $R_L = 50\ \Omega$ , Switch<br>OFF,<br>See <a href="#">Figure 22</a>    | $f = 100\ \text{kHz}$ ,<br>$f = 1\ \text{MHz}$ ,<br>$f = 5\ \text{MHz}$ , | 25°C  | 3.3 V        |     | -70   | dB            |
|                           |                                  |   |   |       |              |     | -50   |               |
|                           |                                  |   |   |       |              |     | -35   |               |
| Crosstalk                 | $X_{TALK}$                       | $R_L = 50\ \Omega$ , Switch<br>ON,<br>See <a href="#">Figure 23</a>     | $f = 100\ \text{kHz}$ ,<br>$f = 1\ \text{MHz}$ ,<br>$f = 5\ \text{MHz}$ , | 25°C  | 3.3 V        |     | -70   | dB            |
|                           |                                  |   |   |       |              |     | -50   |               |
|                           |                                  |   |   |       |              |     | -35   |               |
| Total harmonic distortion | THD                              | $R_L = 600\ \Omega$ ,<br>$C_L = 50\ \text{pF}$ ,                        | $f = 20\ \text{Hz to }20\ \text{kHz}$ ,<br>See <a href="#">Figure 25</a>  | 25°C  | 3.3 V        |     | 0.01  | %             |
| <b>Supply</b>             |                                  |   |   |       |              |     |       |               |
| Positive supply current   | $I_+$                            | $V_I = 1.8\ \text{V}$ or GND  |   | Full  | 3.6 V        |     | 6 13  | $\mu\text{A}$ |

**ELECTRICAL CHARACTERISTICS FOR 5-V SUPPLY<sup>(1)</sup>**
 $V_+ = 4.5\text{ V to }5.5\text{ V}$ ,  $T_A = -40^\circ\text{C to }85^\circ\text{C}$  (unless otherwise noted)

| PARAMETER  | SYMBOL                     | TEST CONDITIONS  |  | $T_A$ | $V_+$ | MIN         | TYP   | MAX   | UNIT          |
|--|----------------------------|--|--|-------|-------|-------------|-------|-------|---------------|
| <b>Analog Switch</b>                                 |                            |  |  |       |       |             |       |       |               |
| Analog signal range                                  | $V_{COM}, V_{NO}, V_{NC}$  |  |  |       |       | $V_+ - 5.5$ |       | $V_+$ | $\Omega$      |
| ON-state resistance                                  | $r_{on}$                   | $V_{NC}$ or $V_{NO} = V_+, 1.5\text{V}, V_+ - 5.5\text{V}$<br>$I_{COM} = -100\text{ mA}$ ,   | Switch ON,<br>See <a href="#">Figure 15</a>  | 25°C  | 4.5 V |             | 0.7   | 1     | $\Omega$      |
|  |                            |  |  | Full  |       |             |       | 1.36  |               |
| ON-state resistance match between channels           | $\Delta r_{on}$            | $V_{NC}$ or $V_{NO} = 1.5\text{ V}$ ,<br>$I_{COM} = -100\text{ mA}$ ,  | Switch ON,<br>See <a href="#">Figure 15</a>  | 25°C  | 4.5 V |             | 0.1   | 0.2   | $\Omega$      |
|  |                            |  |  | Full  |       |             |       | 0.3   |               |
| ON-state resistance flatness                         | $r_{on(flat)}$             | $V_{NC}$ or $V_{NO} = V_+, 1.5\text{V}, V_+ - 5.5\text{V}$<br>$I_{COM} = -100\text{ mA}$ ,   | Switch ON,<br>See <a href="#">Figure 16</a>  | 25°C  | 4.5 V |             | 0.135 | 0.37  | $\Omega$      |
|  |                            |  |  | Full  |       |             |       | 0.51  |               |
| NC, NO OFF leakage current                           | $I_{NC(OFF)}, I_{NO(OFF)}$ | $V_{NC} = 4.5, V_+ - 5.5\text{ V}$<br>$V_{COM} = V_+ - 5.5\text{ V}, 4.5,$<br>$V_{NO} = \text{Open},$<br>or<br>$V_{NO} = 4.5, V_+ - 5.5\text{ V}$<br>$V_{COM} = V_+ - 5.5\text{ V}, 4.5,$<br>$V_{NC} = \text{Open},$ | Switch OFF,<br>See <a href="#">Figure 16</a> | 25°C  | 5.5 V | -50         |       | 50    | nA            |
|  |                            |  |  | Full  |       |             | -375  |       |               |
| COM ON leakage current                               | $I_{COM(ON)}$              | $V_{NC}$ and $V_{NO} = \text{Open},$<br>$V_{COM} = V_+, V_+ - 5.5\text{ V},$   | Switch ON,<br>See <a href="#">Figure 17</a>  | 25°C  | 5.5 V | -50         |       | 50    | nA            |
|  |                            |  |  | Full  |       |             | -375  |       |               |
| <b>Digital Control Inputs (IN, EN)<sup>(2)</sup></b> |                            |  |  |       |       |             |       |       |               |
| Input logic high                                     | $V_{IH}$                   |  |  | Full  |       | 1.05        |       | 5.5   | V             |
| Input logic low                                      | $V_{IL}$                   |  |  | Full  |       |             |       | 0.65  | V             |
| Input leakage current                                | $I_{IH}, I_{IL}$           | $V_{IN} = 1.8\text{ V or }0$   |  | 25°C  | 5.5 V | -1.5        |       | 1.5   | $\mu\text{A}$ |
|  |                            |  |  | Full  |       |             | -1.5  |       |               |

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

(2) All unused digital inputs of the device must be held at  $V_+$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

**ELECTRICAL CHARACTERISTICS FOR 5-V SUPPLY<sup>(1)</sup> (continued)**
 $V_+ = 4.5 \text{ V to } 5.5 \text{ V}$ ,  $T_A = -40^\circ\text{C to } 85^\circ\text{C}$  (unless otherwise noted)

| PARAMETER                 | SYMBOL                           | TEST CONDITIONS   |   | $T_A$ | $V_+$          | MIN | TYP  | MAX | UNIT          |
|---------------------------|----------------------------------|---|---|-------|----------------|-----|------|-----|---------------|
| <b>Dynamic</b>            |                                  |   |   |       |                |     |      |     |               |
| Turn-on time              | $t_{ON}$                         | $V_{COM} = V_+$ ,<br>$R_L = 300 \Omega$ ,                               | $C_L = 35 \text{ pF}$ ,<br>See <a href="#">Figure 19</a>                  | 25°C  | 5 V            | 230 | 374  |     | ns            |
|                           |                                  |   |   | Full  | 4.5 V to 5.5 V |     | 470  |     |               |
| Turn-off time             | $t_{OFF}$                        | $V_{COM} = V_+$ ,<br>$R_L = 300 \Omega$ ,                               | $C_L = 35 \text{ pF}$ ,<br>See <a href="#">Figure 19</a>                  | 25°C  | 5 V            | 206 | 325  |     | ns            |
|                           |                                  |   |   | Full  | 4.5 V to 5.5 V |     | 380  |     |               |
| Break-before-make time    | $t_{BBM}$                        | $V_{NC} = V_{NO} = V_+/2$ ,<br>$R_L = 300 \Omega$ ,                     | $C_L = 35 \text{ pF}$ ,<br>See <a href="#">Figure 20</a>                  | 25°C  | 3.3 V          | 1   | 3    |     | ns            |
| Charge injection          | $Q_C$                            | $V_{GEN} = 0$ ,<br>$R_{GEN} = 0$ ,                                      | $C_L = 1 \text{ nF}$ ,<br>See <a href="#">Figure 24</a>                   | 25°C  | 5 V            |     | 168  |     | pC            |
| NC, NO OFF capacitance    | $C_{NC(OFF)}$ ,<br>$C_{NO(OFF)}$ | $V_{NC}$ or $V_{NO} = V_+$ or<br>$V_+ - 5.5 \text{ V}$ ,<br>Switch OFF, | See <a href="#">Figure 18</a>   | 25°C  | 5 V            |     | 48   |     | pF            |
| NC, NO ON capacitance     | $C_{NC(ON)}$ ,<br>$C_{NO(ON)}$   | $V_{NC}$ or $V_{NO} = V_+$ or<br>$V_+ - 5.5 \text{ V}$ ,<br>Switch ON,  | See <a href="#">Figure 18</a>   | 25°C  | 5 V            |     | 176  |     | pF            |
| COM ON capacitance        | $C_{COM(ON)}$                    | $V_{COM} = V_+$ or GND,<br>Switch ON,                                   | See <a href="#">Figure 18</a>   | 25°C  | 5 V            |     | 176  |     | pF            |
| Digital input capacitance | $C_I$                            | $V_I = V_+$ or GND  | See <a href="#">Figure 18</a>   | 25°C  | 5 V            |     | 3    |     | pF            |
| Bandwidth                 | BW                               | $R_L = 50 \Omega$ ,   | Switch ON,<br>See <a href="#">Figure 20</a>                               | 25°C  | 5 V            |     | 32   |     | MHz           |
| OFF isolation             | $O_{ISO}$                        | $R_L = 50 \Omega$ , Switch OFF,<br>See <a href="#">Figure 22</a>        | $f = 100 \text{ kHz}$   | 25°C  | 5 V            |     | -70  |     | dB            |
|                           |                                  |   | $f = 1 \text{ MHz}$   |       |                |     | -50  |     |               |
|                           |                                  |   | $f = 5 \text{ MHz}$   |       |                |     | -35  |     |               |
| Crosstalk                 | $X_{TALK}$                       | $R_L = 50 \Omega$ , Switch ON,<br>See <a href="#">Figure 23</a>         | $f = 100 \text{ kHz}$   | 25°C  | 5 V            |     | -70  |     | dB            |
|                           |                                  |   | $f = 1 \text{ MHz}$   |       |                |     | -50  |     |               |
|                           |                                  |   | $f = 5 \text{ MHz}$   |       |                |     | -35  |     |               |
| Total harmonic distortion | THD                              | $R_L = 600 \Omega$ ,<br>$C_L = 50 \text{ pF}$ ,                         | $f = 20 \text{ Hz to } 20 \text{ kHz}$ ,<br>See <a href="#">Figure 25</a> | 25°C  | 5 V            |     | 0.01 |     | %             |
| <b>Supply</b>             |                                  |   |   |       |                |     |      |     |               |
| Positive supply current   | $I_+$                            | $V_I = 1.8 \text{ V or GND}$  |   | Full  | 5.5 V          |     | 7    | 14  | $\mu\text{A}$ |

TYPICAL PERFORMANCE

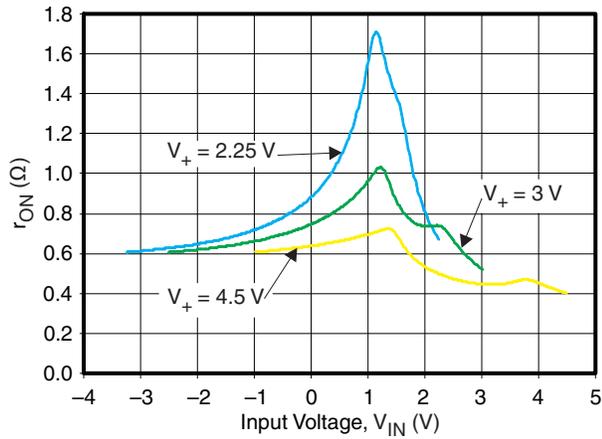


Figure 2.  $r_{on}$  vs  $V_{IN}$

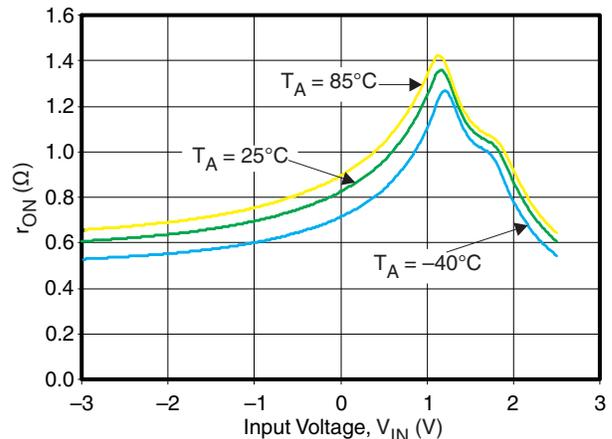


Figure 3.  $r_{on}$  vs  $V_{IN}$  ( $V_+ = 2.5$  V)

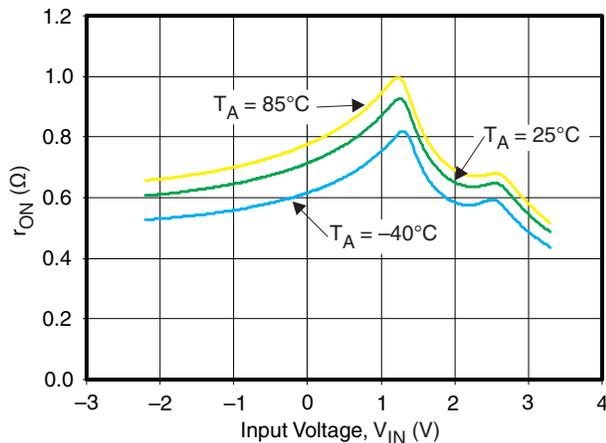


Figure 4.  $r_{on}$  vs  $V_{IN}$  ( $V_+ = 3.3$  V)

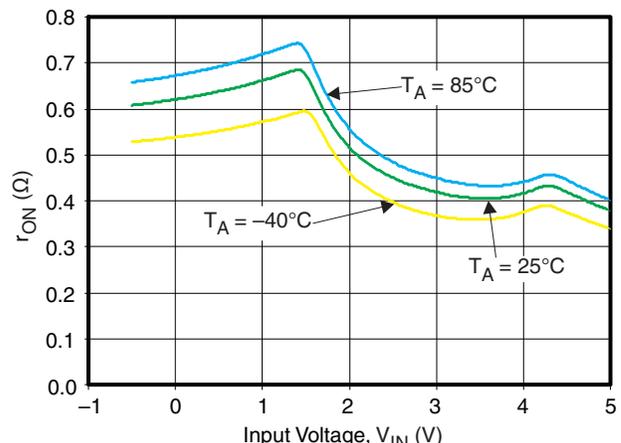


Figure 5.  $r_{on}$  vs  $V_{IN}$  ( $V_+ = 5$  V)

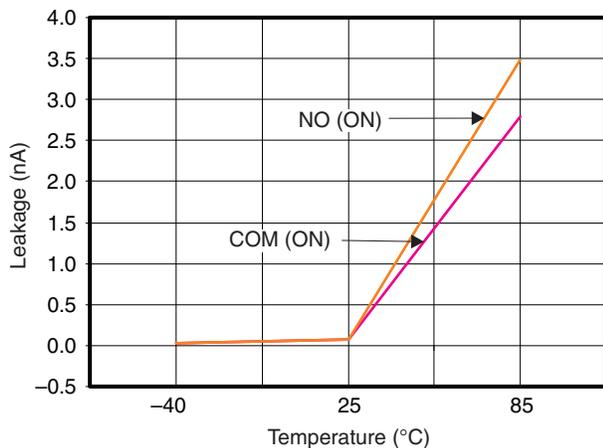


Figure 6. Leakage Current vs Temperature

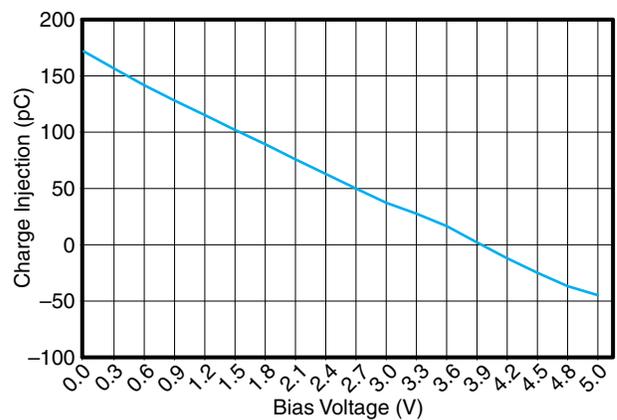


Figure 7. Charge Injection ( $Q_C$ ) vs  $V_{COM}$  ( $V_+ = 5$  V)

TYPICAL PERFORMANCE (continued)

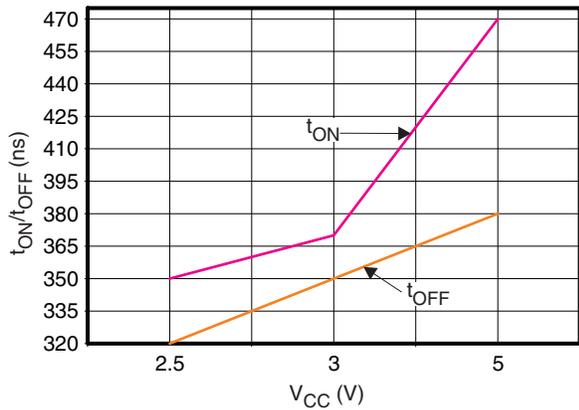


Figure 8.  $t_{ON}$  and  $t_{OFF}$  vs Supply Voltage

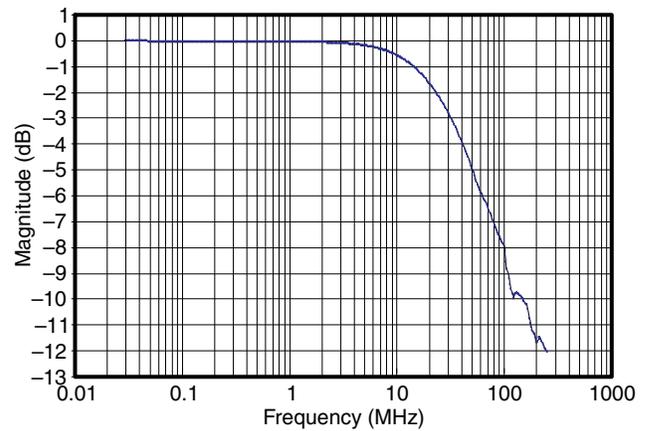


Figure 9. Bandwidth ( $V_+ = 2.5\text{ V}$ )

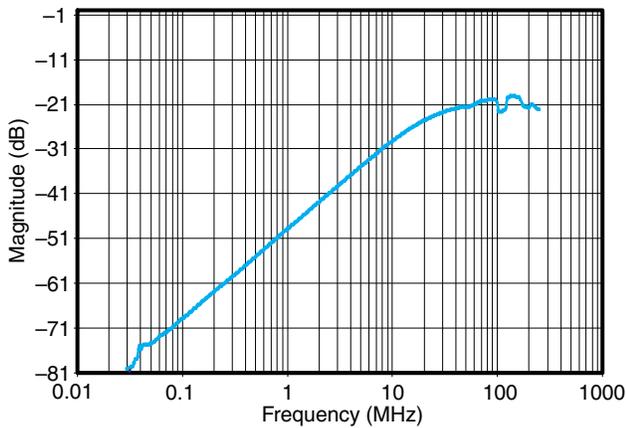


Figure 10. OFF Isolation vs Frequency

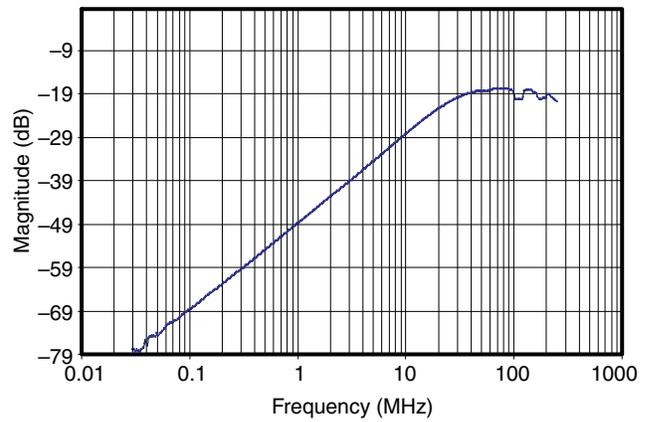


Figure 11. Crosstalk ( $V_+ = 3.3\text{ V}$ )

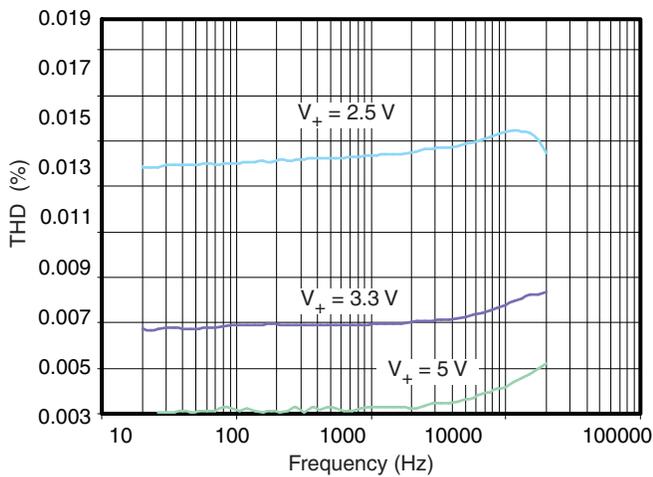


Figure 12. Total Harmonic Distortion vs Frequency

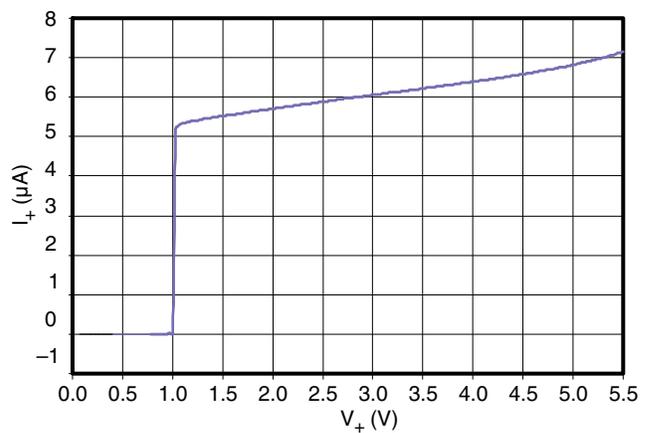


Figure 13. Power-Supply Current vs  $V_+$

**TYPICAL PERFORMANCE (continued)**

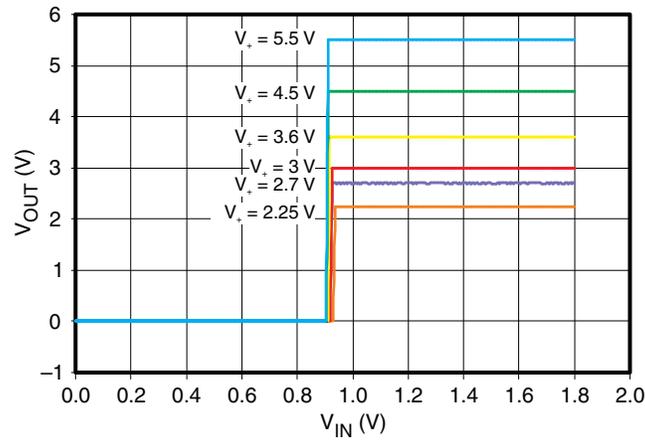


Figure 14. Control Input Thresholds

PARAMETER MEASUREMENT INFORMATION

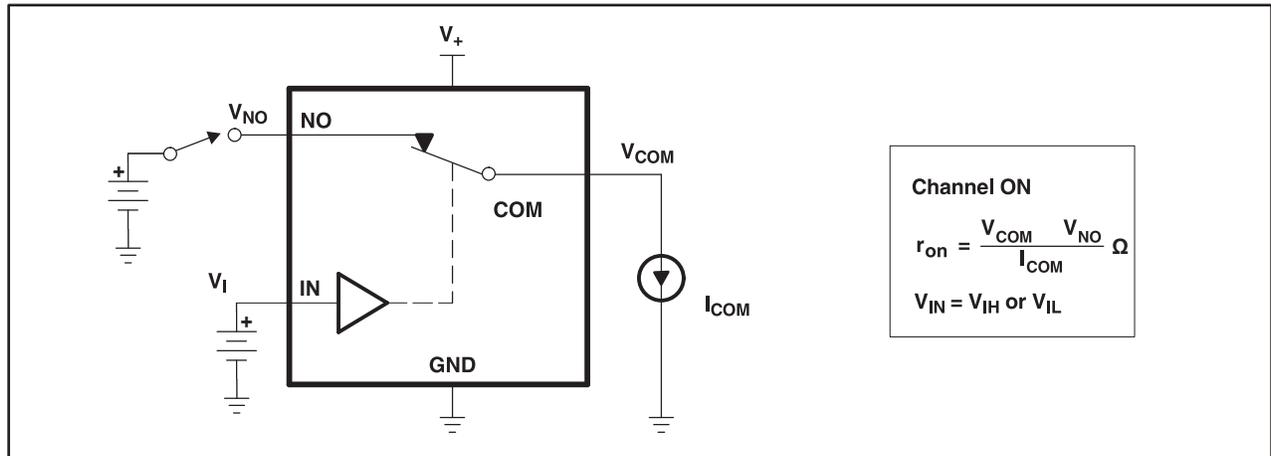


Figure 15. ON-state Resistance ( $r_{ON}$ )

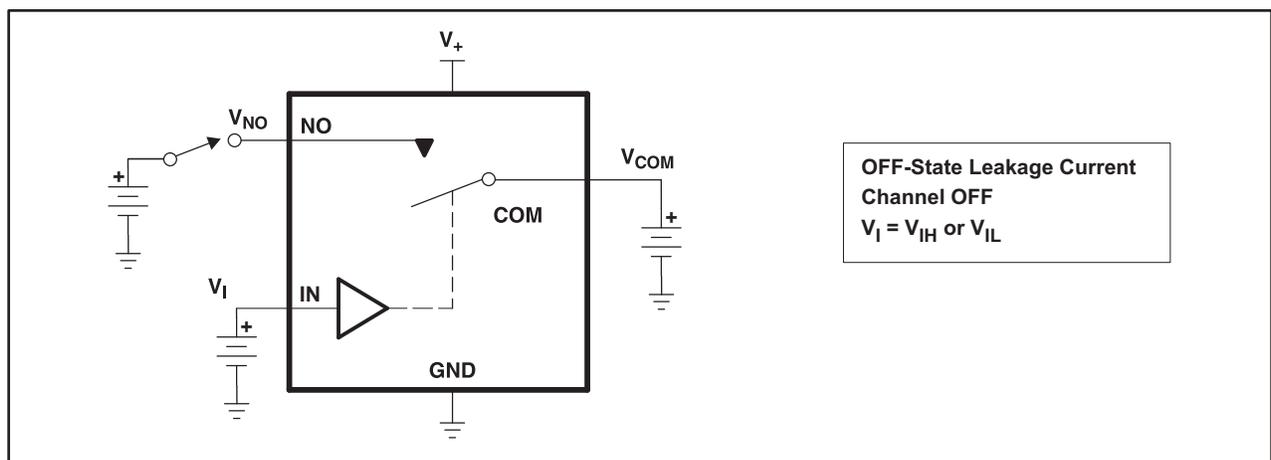


Figure 16. OFF-State Leakage Current  
( $I_{COM(OFF)}$ ,  $I_{NC(OFF)}$ ,  $I_{COM(PWROFF)}$ ,  $I_{NC(PWROFF)}$ )

PARAMETER MEASUREMENT INFORMATION (continued)

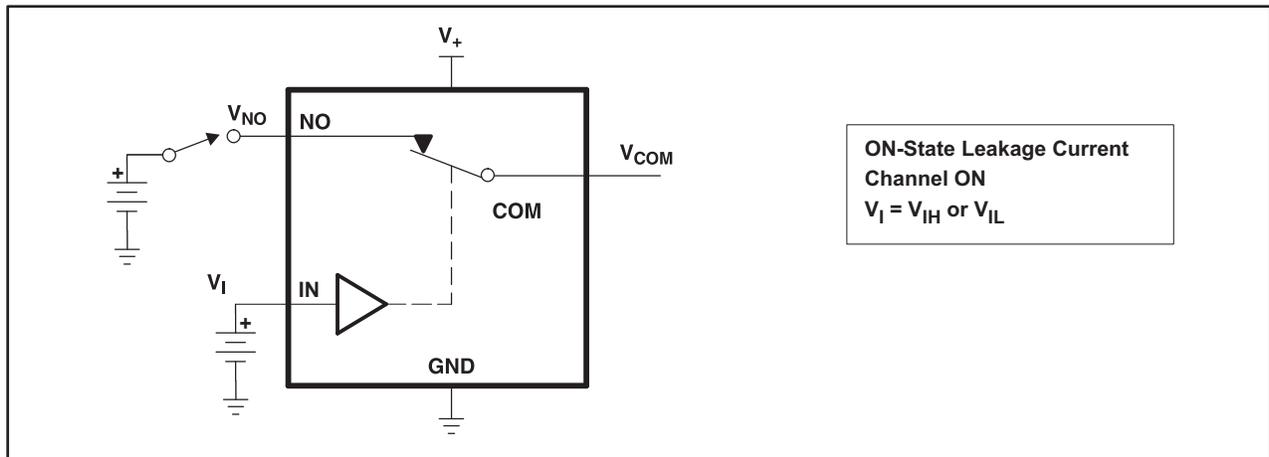


Figure 17. ON-State Leakage Current  
( $I_{COM(ON)}$ ,  $I_{NC(ON)}$ )

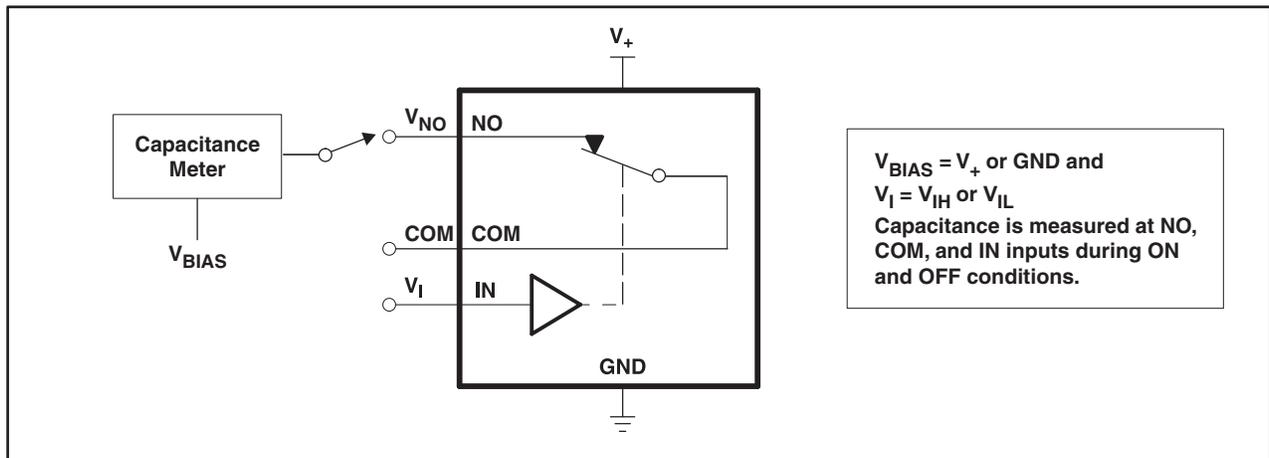


Figure 18. Capacitance  
( $C_I$ ,  $C_{COM(OFF)}$ ,  $C_{COM(ON)}$ ,  $C_{NC(OFF)}$ ,  $C_{NC(ON)}$ )

- A. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10$  MHz,  $Z_O = 50 \Omega$ ,  $t_r < 5$  ns,  $t_f < 5$  ns.
- B.  $C_L$  includes probe and jig capacitance.

PARAMETER MEASUREMENT INFORMATION (continued)

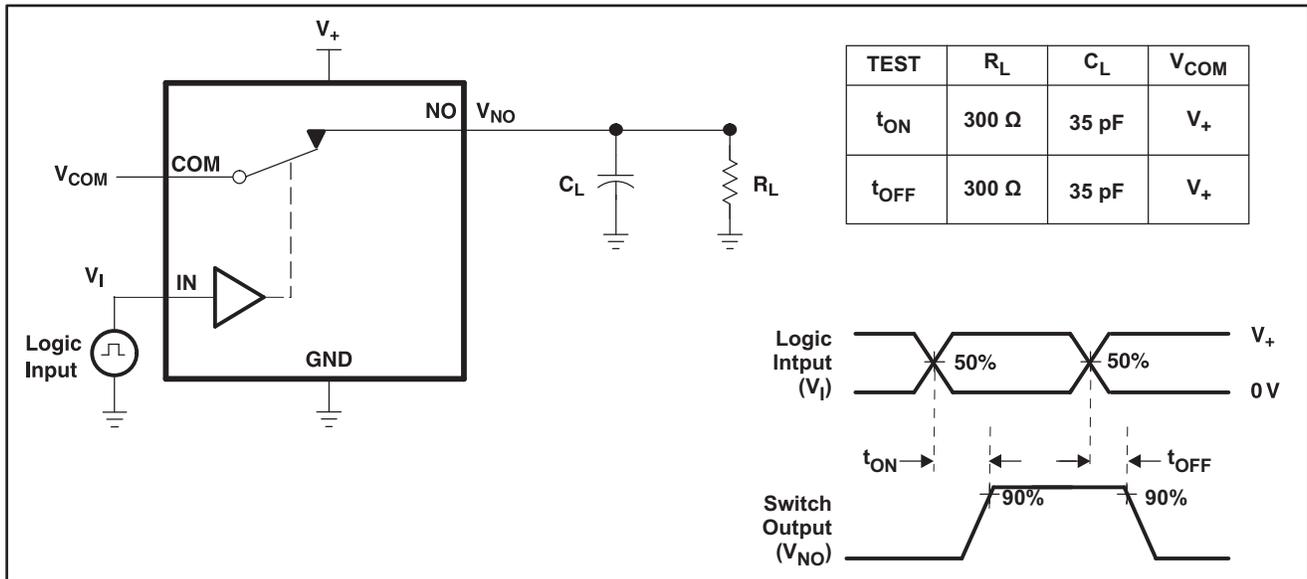


Figure 19. Turn-On (t<sub>ON</sub>) and Turn-Off Time (t<sub>OFF</sub>)

- A. C<sub>L</sub> includes probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z<sub>O</sub> = 50 Ω, t<sub>r</sub> < 5 ns, t<sub>f</sub> < 5 ns.

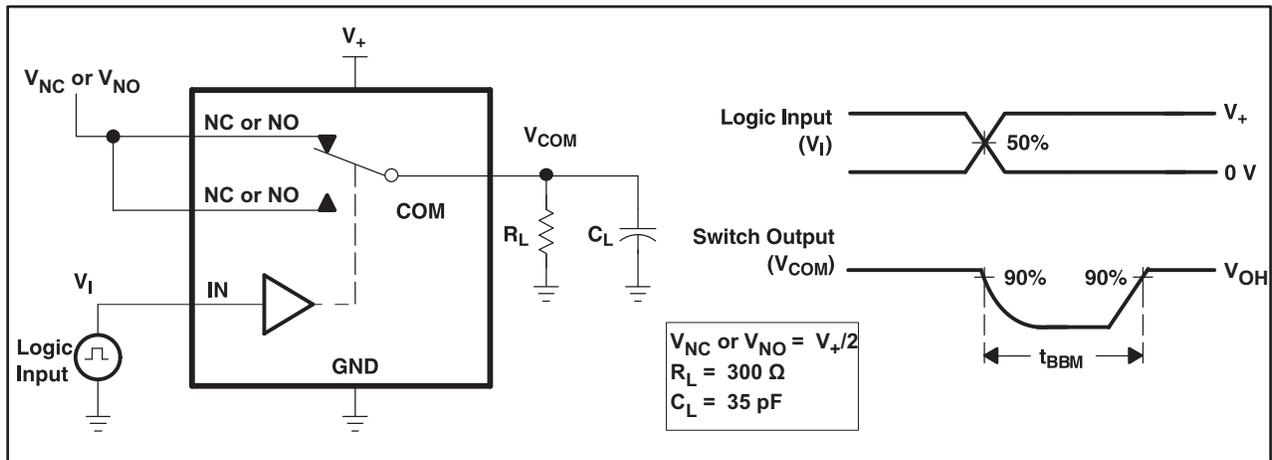


Figure 20. Break-Before-Make Time (t<sub>BBM</sub>)

PARAMETER MEASUREMENT INFORMATION (continued)

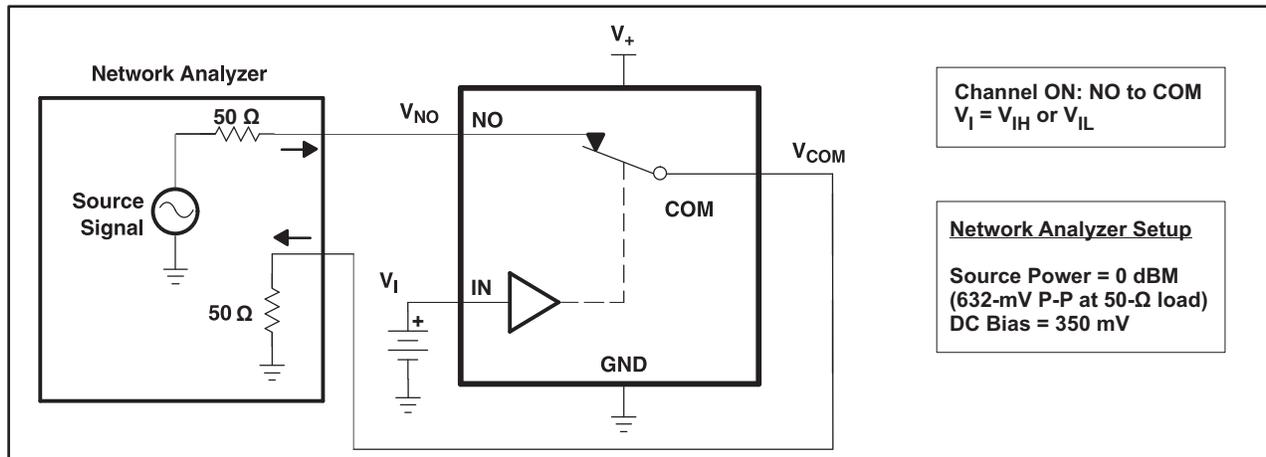


Figure 21. Bandwidth (BW)

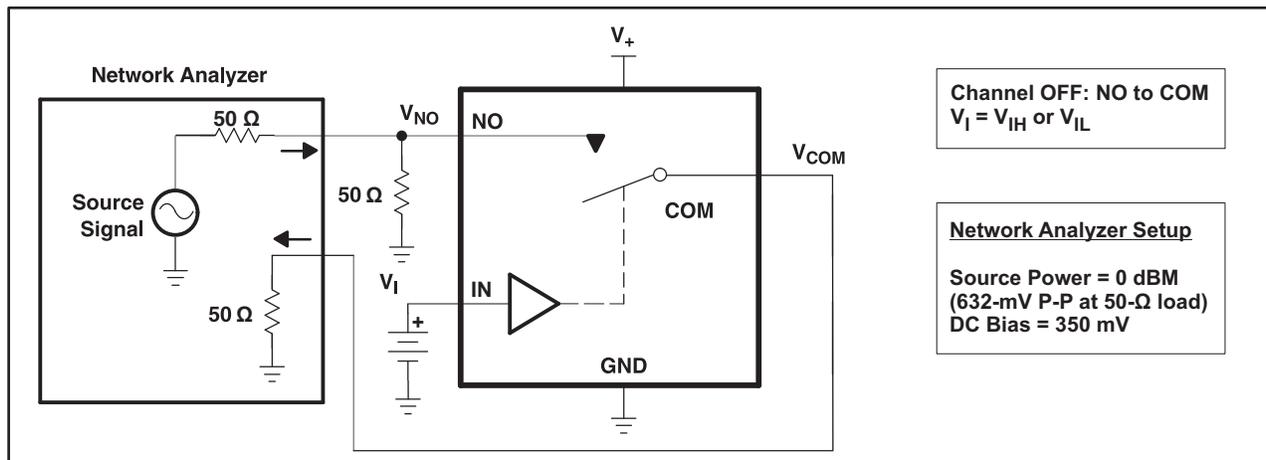


Figure 22. OFF Isolation ( $O_{ISO}$ )

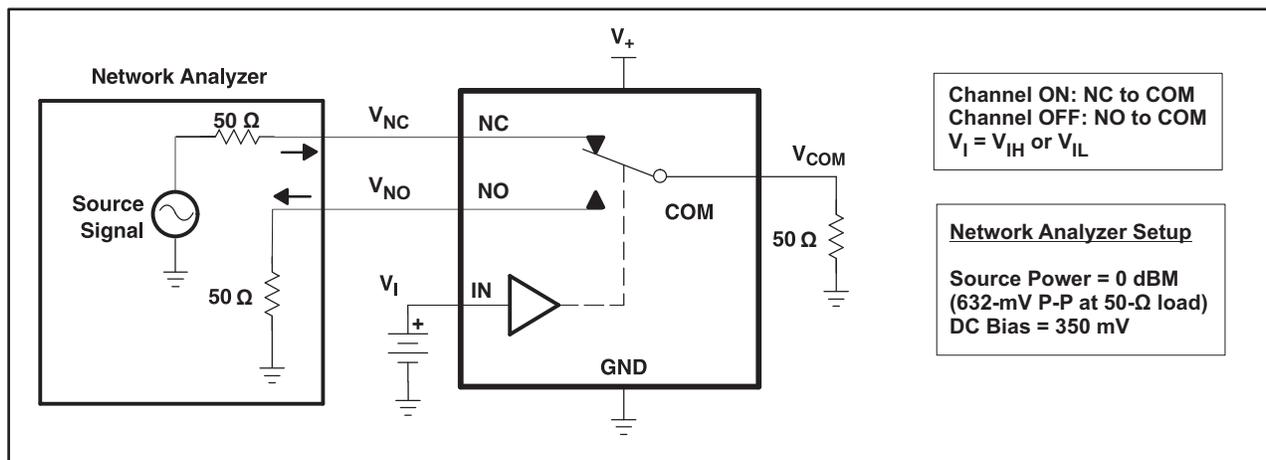


Figure 23. Crosstalk ( $X_{TALK}$ )

- A. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_0 = 50 \Omega$ ,  $t_r < 5$  ns,  $t_f < 5$  ns.
- B.  $C_L$  includes probe and jig capacitance.

PARAMETER MEASUREMENT INFORMATION (continued)

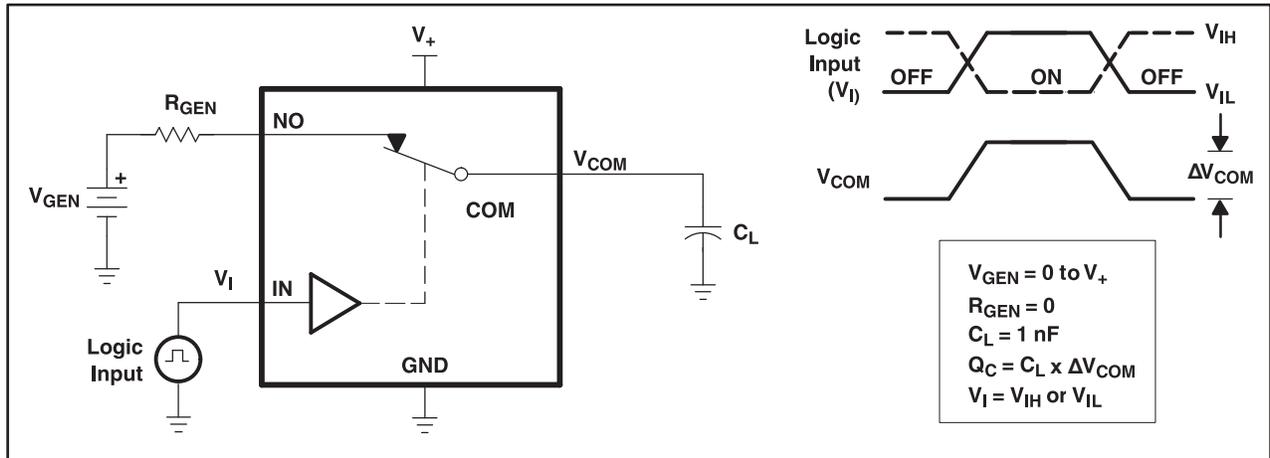


Figure 24. Charge Injection ( $Q_C$ )

A.  $C_L$  includes probe and jig capacitance.

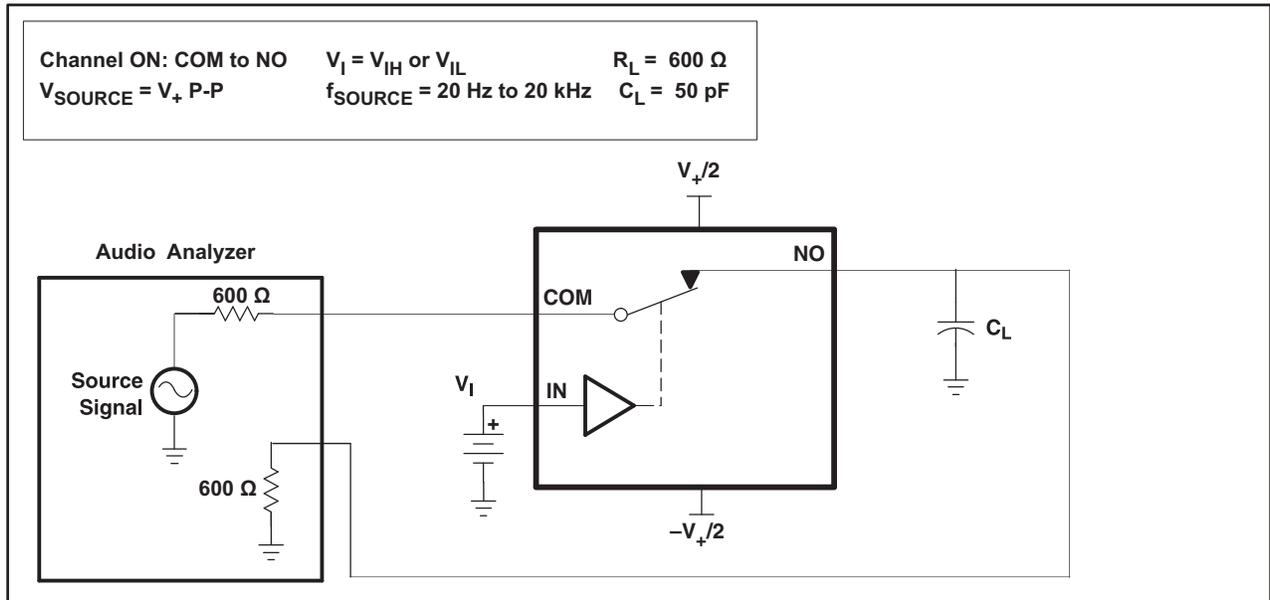


Figure 25. Total Harmonic Distortion (THD)

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**REVISION HISTORY**

| <b>Changes from Revision A (August 2009) to Revision B</b>                    | <b>Page</b> |
|---|-------------|
| • Removed QFN reference from product description. ....                        | <b>1</b>    |
| • Changed Analog signal range MIN value from $V_+ - 0.5$ to $V_+ - 5.5$ ..... | <b>7</b>    |

---

**PACKAGING INFORMATION**

| Orderable Device | Status<br>(1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan<br>(2)         | Lead/Ball Finish | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|-----------------|------|-------------|-------------------------|------------------|----------------------|--------------|-------------------------|-------------------------|
| TS5A22366YFCR    | ACTIVE        | DSBGA        | YFC             | 12   | 3000        | Green (RoHS & no Sb/Br) | SNAGCU           | Level-1-260C-UNLIM   | -40 to 85    | 3A2                     | <a href="#">Samples</a> |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

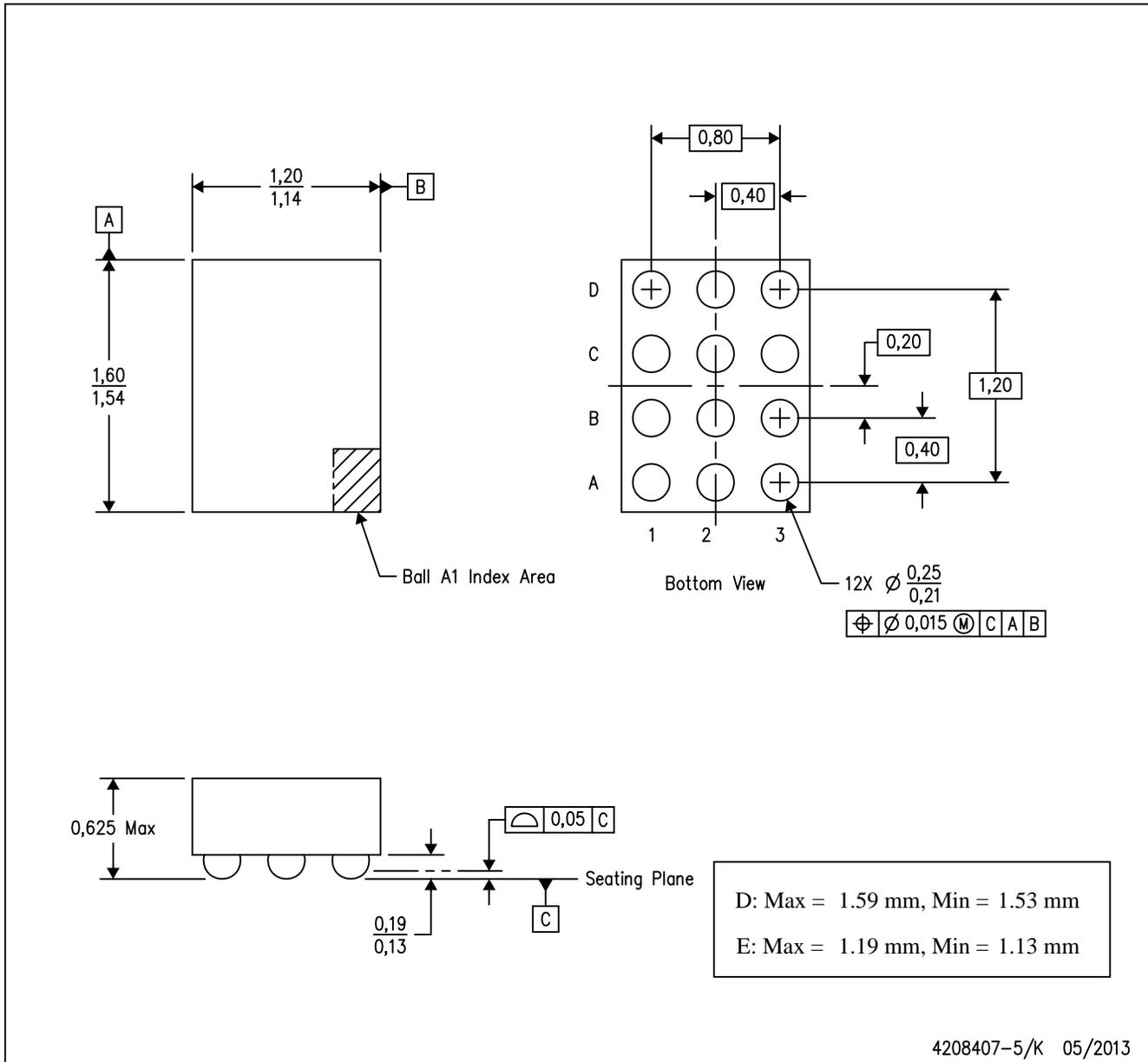
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# MECHANICAL DATA

YFC (R-XBGA-N12)

DIE-SIZE BALL GRID ARRAY



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. NanoFree™ package configuration.

NanoFree is a trademark of Texas Instruments.

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|                               |  |
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